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Electrodeposition of pure nanometric CeO₂ and Bi₂O₃ thin films for electrodegradation of organic pollutants

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Abstract

Pollution with different types is one of the major problems that threaten our planet. Very large amounts of pollutants are emitted worldwide and cause

to the health of the humans and the environment, which will cause a decrease in resources for sustainable development of the planet. It is therefore essential to seek scientific solutions to reduce these hazardous emissions. In this context, the development of new materials to detect and clean up liquid and gas emissions from all sources is inevitable. The rare earth oxides have been used for many years to improve the reactivity, selectivity and stability of the catalysts. These oxides include cerium and bismuth oxide, which have been electrodeposited on several substrates under galvanostatic condition from aqueous solutions. The X-Ray diffraction (XRD) and scanning electron microscopy (SEM) studies revealed that as deposited films are nanocristalline, and the films are porous and the surface morphology changes with variation of several parameters (Current, substrate...).

Keywords: Electrodeposition, nanocristalline, electrodegradation, organic pollutants.

Introduction

Thanks to his interesting properties, Cerium oxide has been used in different applications. It is used as main components of the three-way catalysts, to remove, unwanted sulfur oxide, for the treatment of waste water and for the improvement of catalytic properties...

Processing techniques such as sputtering, chemical vapor deposition, sol-gel processing and electrodeposition has been used for the formation of cerium oxide films. The electrodeposition has received considerable attention since the deposition can be carried out at low temperatures and pressure also relatively lower.

The electrodeposition of thin films can be performed with the base generation deposition method on several metallic substrates as Aluminium and Aluminium alloys, stainless steel, and titanium.

Thin films of cerium were already synthesized and studied by Hamlaoui and Zivkovic [1,2]. Bi₂O₃ was electrodeposited, studied and tested for use in the electrochemical supercapacitors by Gujar [3].

2. Materials and methods

Plates of 1mm thick are cut to form discs of 14 mm of diameter. Substrates were subjected to a polishing by abrasive paper 800 and 1200, rinsed with distilled water and ethanol.

2.1. Synthesis

The electrochemical bath containing the solution of Cerium nitrates $(Ce(NO_3)_3.6H_2O)$ or Bismuth nitrates $(Bi(NO_3)_3.5H_2O)$ 0.1 M at room temperature [4]. The electrodeposition is done by the three electrode assembly; the metal substrate is the cathode, the platinum electrode as the counter electrode and the saturated calomel electrode as reference electrode. The deposition is done by the galvanostatic mode without stirring the

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solution. Chronopotentiometry technique is used to deposit with a constant current density 5mA. After électrodeposition, the samples were rinsed in ethanol and dried in desiccators before any further subsequent analysis.

2.2. Characterization techniques

The morphology of the films was studied by scanning electron microscopy (SEM) coupled with EDX analysis. The X-ray diffractograms of the samples are obtained by a diffractometer PANALYTICAL EMPYREAN provided with a copper anticathode. The crystallite size "D" was calculated from the Sherrer equation (D=0.9 λ / β cos θ), for the most intense peaks (where λ is the wavelength of the X-ray, β is the full width at half maximum of the peak and θ is the diffraction angle).

3. Results and discussion

3.1. Ceria thin films

3.1.1. X-ray results

Pure ceria layer deposited on the aluminum substrate is characterized from structural side by XRD shaving in an angular range between 20 and 60 degrees. Figure 1 shows the diffraction pattern obtained with the crystalline phases that appear.

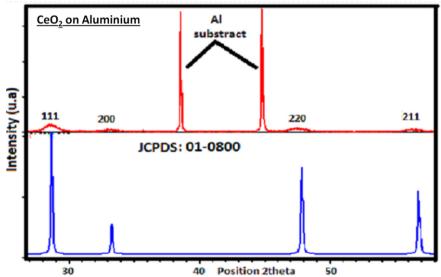


Figure 1: XRD patterns of the cerium oxide films elaborated at current density of 5 mA cm⁻¹ for 120 min in 0.1 M Ce(NO₃)₃ is in agreement with the JCPDS card no 01-0800.

By analyzing the spectrum obtained with the software X'Pert HighScore, there is more than one part of the aluminum substrate and ceria; we have the presence of the phase Al_2O_3 which is formed by oxidation of the substrate. On the other hand, the rays of ceria are very broad, which shows that the grains electrodeposited are nanometric.

The calculated value of the crystallite size for this sample is between 30 nm. The following table shows the crystallite sizes for the different peaks.

Table 1: Crystallite size of CeO₂ calculated by the Scherer equation

2θ (°)	FWHM (°)	D (nm)
28.51	0.12	69.4
32.97	0.55	15.0
47.57	0.77	11.3
56.32	1.15	7.8

3.1.2 Microstructural analysis

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Figures 2.a and 2.b show that the thin layer of ceria contains cracks which are formed during heat treatment and are probably due to the departure of the organic phase or water molecules. The clusters vary in size and have the order of 100 microns.

Enlargement of clusters (Figures 2.c and 2.d) shows that they are composed of very small grains in the zone of the cerium oxide. The composition of the deposited films was confirmed by EDX (figure 2.f).

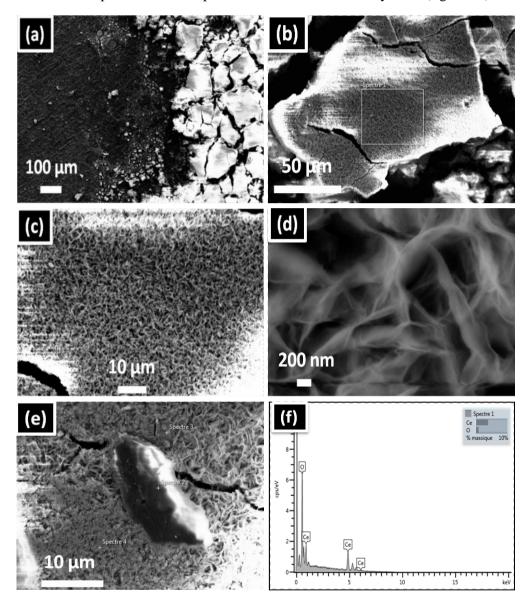


Figure 2: SEM images of CeO₂ deposited on aluminum (a, b, c, d, e); (f): X-ray microanalysis spectrum of (b)

3.2 Bismuth oxide thin films

3.2.1 X-ray results

The thin films of bismuth oxide Bi_2O_3 synthesized were analyzed by XRD. The diffractogram obtained for this deposit is presented in the following figure:

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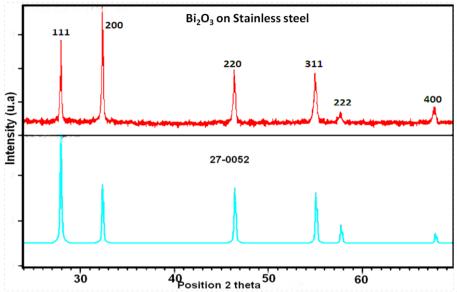


Figure 3: XRD patterns of the bismuth oxide films elaborated at current density of 5 mA cm⁻¹ for 120 min in 0.1 M Bi(NO₃)₃ is in agreement with the JCPDS card no 27-0052.

By analyzing the spectrum obtained with X'Pert HighScore software, it is clear that we synthesized the bismuth oxide δ -Bi₂O₃. We can see the occurrence of most of the lines corresponding to the bismuth oxide with nanometric size.

3.2.2 Microstructural analysis

To determine the morphology of the sample prepared, we conducted a study by Scanning Electron Microscopy. Figure 4 (a, b, c) shows the images obtained with secondary electrons.

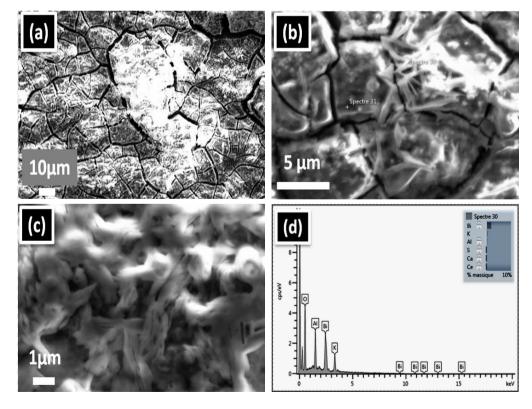


Figure 4: SEM images of the bismuth oxide Bi2O3 (a, b, c); (d):X-ray microanalysis spectrum of (c)

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Figure 4.a represents an overview of the thin film and shows a fairly uniform distribution of bismuth oxide deposited. There is an homogenous morphology but with cracks between clusters of the studied material. In figure 4.b we observed clusters of micrometric size. However, by magnifying the image (figure 4.c) shows that the layer is in the form of small grains bonded shapes and sizes. EDX analysis confirms the synthesis of Bi_2O_3 (figure 4.d).

Conclusion

Pure Ceria and Bismuth thin films are synthesized with catalytic properties able to be integrated into devices of pollution control wastewater. The samples were prepared by electrodeposition on several substrates (Aluminium, Stainless steel and Copper) and these heat-treated at 400-450°C. Thin films obtained were characterized by X-ray diffraction (XRD) and scanning electron microscopy (SEM).

These analyses confirmed the deposition of catalytic phase pure CeO_2 and δ -Bi₂O₃ thin films on an aluminum and stainless substrate.

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